Low-power 1-of-2 demultiplexer with 3-state deselected output

Rev. 5 — 3 July 2012

**Product data sheet** 

### 1. General description

The 74AUP1G18 provides a 1-of-2 non-inverting demultiplexer with 3-state output. The 74AUP1G18 buffers the data on input pin (A) and passes it either to output 1Y or 2Y, depending on whether the state of the select input pin (S) is LOW or HIGH.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \ \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

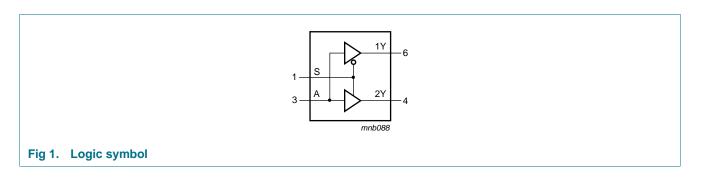
Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G18GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1G18GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886
74AUP1G18GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891
74AUP1G18GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1G18GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202

### 4. Marking

Table 2. Marking	
Type number	Marking code <sup>[1]</sup>
74AUP1G18GW	рW
74AUP1G18GM	рW
74AUP1G18GF	рW
74AUP1G18GN	рW
74AUP1G18GS	рW

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

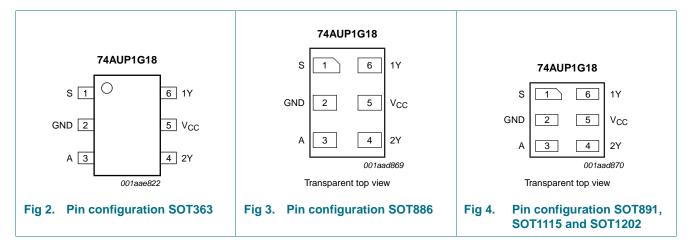
### 5. Functional diagram



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### 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
S	1	data select
GND	2	ground (0 V)
А	3	data input
2Y	4	data output
V <sub>CC</sub>	5	supply voltage
1Y	6	data output

### 7. Functional description

#### Table 4.Function table<sup>[1]</sup>

Input		Output	
S	Α	1Y	2Y
L	L	L	Z
L	Н	Н	Z
Н	L	Z	L
Н	Н	Z	Н

[1] H = HIGH voltage level;

L = LOW voltage level;

Z = high-impedance OFF-state.

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#### **Limiting values** 8.

#### Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
l <sub>O</sub>	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K. For XSON6 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

#### **Recommended operating conditions** 9.

Table 6.	Recommended operating condition	ons			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$	0	200	ns/V

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## **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

oynibol	Parameter	Conditions	Min	Тур	Max	Un
T <sub>amb</sub> = 25	5 °C					
√ <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
√он	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; V <sub>CC</sub> = 0.8 V to 3.6 V	$V_{CC} - 0.1$	-	-	V
		$I_0 = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75  imes V_{CC}$	-	-	V
		$I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_0 = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		$I_{O} = 20 \ \mu$ A; $V_{CC} = 0.8 \ V$ to 3.6 V	-	-	0.1	V
		$I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		$I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
	input leakage current	$V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
OFF	power-off leakage current	$V_{\rm I}$ or $V_{\rm O} = 0$ V to 3.6 V; $V_{\rm CC} = 0$ V	-	-	±0.2	μA
$\Delta I_{OFF}$	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μ/
сс	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
7I <sup>CC</sup>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	40	μΑ
<b>`</b>	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.8	-	рF
Cı						

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### Low-power 1-of-2 demultiplexer with 3-state deselected output

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35\times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V <sub>ОН</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	$V_{CC} - 0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		I <sub>O</sub> = −1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
l	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
$\Delta I_{OFF}$	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I <sub>CC</sub>	supply current	$V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
Δl <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> _	-	50	μΑ

#### Table 7. Static characteristics ... continued

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#### Low-power 1-of-2 demultiplexer with 3-state deselected output

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25\times V_{CC}$	V
		$V_{CC} = 0.9 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.30\times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = –20 $\mu\text{A};$ $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> – 0.11	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6\times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.33\times V_{CC}$	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		$I_0$ = 2.3 mA; $V_{CC}$ = 2.3 V	-	-	0.36	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
I <sub>I</sub>	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μΑ
I <sub>OZ</sub>	OFF-state output current		-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μΑ
$\Delta I_{OFF}$	additional power-off leakage current		-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC};  I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$	-	-	1.4	μΑ
∆l <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> _	-	75	μΑ

#### Table 7. Static characteristics ... continued

[1] One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

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### **11. Dynamic characteristics**

#### Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions			25 °C		–40 °C to +125 °C			Unit
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 5 p	F							1	1	
t <sub>pd</sub>	propagation delay	A to nY; see Figure 5	[2]							
		$V_{CC} = 0.8 V$		-	20.4	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	5.6	10.6	2.4	10.7	10.7	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.4	3.9	6.1	2.2	6.5	6.7	ns
		$V_{CC}$ = 1.65 V to 1.95 V		1.8	3.1	4.7	1.6	5.3	5.6	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.6	2.4	3.6	1.4	4.0	4.2	ns
		$V_{CC}$ = 3.0 V to 3.6 V		1.4	2.2	3.1	1.2	3.4	3.5	ns
t <sub>en</sub>	enable time	S to nY; see Figure 6	[3]		-					
	$V_{CC} = 0.8 V$		-	46.1	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	5.6	9.7	2.9	10.1	11.1	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.5	4.0	6.2	2.2	6.6	7.3	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.1	3.3	5.1	1.8	5.5	6.1	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.7	2.7	3.9	1.4	4.2	4.6	ns
		$V_{CC}$ = 3.0 V to 3.6 V		1.5	2.4	3.5	1.2	3.7	4.1	ns
t <sub>dis</sub>	disable time	S to nY; see Figure 6	[4]							
		$V_{CC} = 0.8 V$		-	12.6	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		3.0	4.7	7.5	2.9	7.9	8.7	ns
		$V_{CC}$ = 1.4 V to 1.6 V		2.3	3.5	5.2	2.2	5.5	6.1	ns
		$V_{CC}$ = 1.65 V to 1.95 V		2.3	3.4	4.8	2.1	5.1	5.6	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.7	2.5	3.6	1.5	3.9	4.3	ns
		$V_{CC}$ = 3.0 V to 3.6 V		2.0	2.9	3.8	1.8	4.1	4.5	ns
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation delay	A to nY; see Figure 5	[2]							
		$V_{CC} = 0.8 V$		-	23.9	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		2.9	6.4	12.2	2.9	12.3	12.3	ns
		$V_{CC}$ = 1.4 V to 1.6 V		2.7	4.5	7.1	2.4	7.6	7.9	ns
		$V_{CC}$ = 1.65 V to 1.95 V		2.3	3.7	5.5	2.1	6.0	6.3	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.9	3.0	4.2	1.8	4.6	4.9	ns
		$V_{CC}$ = 3.0 V to 3.6 V		1.8	2.7	3.9	1.6	4.1	4.3	ns

#### Low-power 1-of-2 demultiplexer with 3-state deselected output

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +1	25 °C	Uni
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	S to nY; see Figure 6	<u>[3]</u>							
		$V_{CC} = 0.8 V$		-	50.1	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		3.6	6.5	11.1	3.3	11.6	12.8	ns
		$V_{CC}$ = 1.4 V to 1.6 V		2.9	4.6	7.0	2.6	7.6	8.4	ns
		$V_{CC}$ = 1.65 V to 1.95 V		2.5	3.9	5.8	2.2	6.3	6.9	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.1	3.2	4.6	1.7	4.9	5.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.0	2.9	4.2	1.6	4.4	4.8	ns
t <sub>dis</sub>	disable time	S to nY; see Figure 6	[4]							
		$V_{CC} = 0.8 V$		-	14.5	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		4.1	5.8	8.7	3.9	9.1	10.0	ns
		$V_{CC}$ = 1.4 V to 1.6 V		3.2	4.4	6.1	3.0	6.5	7.2	ns
		$V_{CC}$ = 1.65 V to 1.95 V		3.3	4.5	6.0	3.2	6.3	6.9	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.4	3.3	4.4	2.2	4.7	5.2	ns
		$V_{CC}$ = 3.0 V to 3.6 V		3.1	4.1	5.2	3.0	5.5	6.1	ns
C <sub>L</sub> = 15 p	ρF									
t <sub>pd</sub> propagation dela	propagation delay	A to nY; see Figure 5	[2]							
		$V_{CC} = 0.8 V$		-	27.4	-				ns
		$V_{CC}$ = 1.1 V to 1.3 V		3.4	7.2	13.7	3.2	13.9	13.9	ns
		$V_{CC}$ = 1.4 V to 1.6 V		3.2	5.0	7.9	2.8	8.7	9.1	ns
		$V_{CC}$ = 1.65 V to 1.95 V		2.5	4.2	6.3	2.4	7.0	7.4	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.3	3.4	4.9	2.2	5.3	5.7	ns
		$V_{CC}$ = 3.0 V to 3.6 V		2.2	3.2	4.4	1.9	4.8	5.0	ns
ten	enable time	S to nY; see Figure 6	[3]							
		$V_{CC} = 0.8 V$		-	53.9	-				ns
		$V_{CC}$ = 1.1 V to 1.3 V		4.1	7.3	12.4	3.6	12.9	14.2	ns
		$V_{CC}$ = 1.4 V to 1.6 V		3.3	5.2	7.8	2.9	8.4	9.2	ns
		$V_{CC}$ = 1.65 V to 1.95 V		2.9	4.4	6.4	2.5	7.0	7.7	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.5	3.6	5.2	2.1	5.5	6.1	ns
		$V_{CC}$ = 3.0 V to 3.6 V		2.3	3.4	4.8	1.9	4.9	5.4	ns
dis	disable time	S to nY; see Figure 6	<u>[4]</u>							
		$V_{CC} = 0.8 V$		-	16.3	-				ns
		$V_{CC}$ = 1.1 V to 1.3 V		5.1	6.9	10.0	4.9	10.4	11.4	ns
		$V_{CC}$ = 1.4 V to 1.6 V		4.0	5.3	7.1	3.8	7.4	8.1	ns
		$V_{CC}$ = 1.65 V to 1.95 V		4.3	5.6	7.3	4.2	7.6	8.4	ns
		$V_{CC}$ = 2.3 V to 2.7 V		3.1	4.1	5.3	3.0	5.6	6.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		4.2	5.3	6.6	4.1	6.9	7.6	ns

#### Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

#### Low-power 1-of-2 demultiplexer with 3-state deselected output

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +12	25 °C	Unit
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	_
C <sub>L</sub> = 30 p	ρF									
t <sub>pd</sub>	propagation delay	A to nY; see Figure 5	[2]							
		$V_{CC} = 0.8 V$		-	37.8	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.1	9.5	18.0	4.1	18.5	18.9	ns
	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		3.7	6.6	10.4	3.8	11.5	12.1	ns	
	$V_{CC}$ = 1.65 V to 1.95 V		3.4	5.5	8.3	3.3	9.2	9.8	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		3.2	4.5	6.3	3.0	6.8	7.3	ns
		$V_{CC}$ = 3.0 V to 3.6 V		3.1	4.2	5.8	2.9	6.6	7.0	ns
t <sub>en</sub>	enable time	S to nY; see Figure 6	<u>[3]</u>							
		$V_{CC} = 0.8 V$		-	66.3	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		5.3	9.6	16.4	4.7	17.0	18.7	ns
		$V_{CC}$ = 1.4 V to 1.6 V		4.4	6.8	10.0	3.9	10.9	12.0	ns
		$V_{CC}$ = 1.65 V to 1.95 V		4.0	5.7	8.2	3.4	8.9	9.8	ns
		$V_{CC}$ = 2.3 V to 2.7 V		3.4	4.8	6.6	2.9	7.0	7.7	ns
		$V_{CC}$ = 3.0 V to 3.6 V		3.2	4.5	6.1	2.8	6.5	7.2	ns
dis	disable time	S to nY; see Figure 6	<u>[4]</u>							
		$V_{CC} = 0.8 V$		-	21.8	-	-	-	-	ns
		$V_{CC}$ = 1.1 V to 1.3 V		8.2	10.4	14.3	8.0	14.7	16.2	ns
		$V_{CC}$ = 1.4 V to 1.6 V		6.5	8.0	10.0	6.3	10.4	11.4	ns
		$V_{CC}$ = 1.65 V to 1.95 V		7.4	9.0	11.0	7.3	11.3	12.4	ns
		$V_{CC}$ = 2.3 V to 2.7 V		5.3	6.5	7.9	5.2	8.2	9.0	ns
		$V_{CC}$ = 3.0 V to 3.6 V		7.6	9.0	10.7	7.4	11.0	12.1	ns

#### Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

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#### Low-power 1-of-2 demultiplexer with 3-state deselected output

#### Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>.

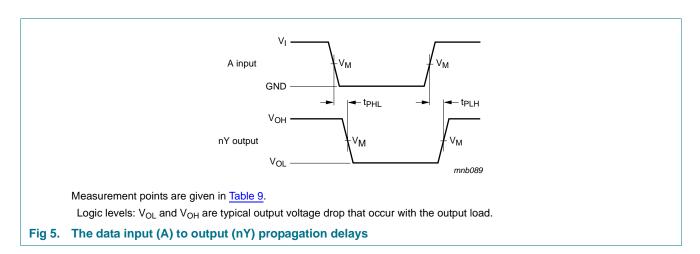
Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C			Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	-
C <sub>L</sub> = 5 pl	F, 10 pF, 15 pF and	30 pF								
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[5]</u>							
		$V_{CC} = 0.8 V$		-	2.8	-	-	-	-	pF
		$V_{CC}$ = 1.1 V to 1.3 V		-	2.9	-	-	-	-	pF
		$V_{CC}$ = 1.4 V to 1.6 V		-	3.0	-	-	-	-	pF
		$V_{CC}$ = 1.65 V to 1.95 V		-	3.2	-	-	-	-	pF
		$V_{CC}$ = 2.3 V to 2.7 V		-	3.7	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	4.2	-	-	-	-	pF

[1] All typical values are measured at nominal  $V_{\text{CC}}.$ 

- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [4]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$  = sum of the outputs.

### 12. Waveforms

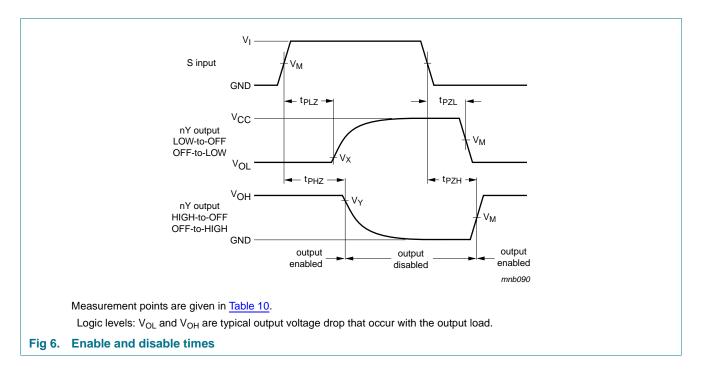


#### Table 9.Measurement points

Supply voltage Output		Input				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>		
0.8 V to 3.6 V	$0.5  imes V_{CC}$	$0.5\times V_{CC}$	V <sub>CC</sub>	≤ 3.0 ns		

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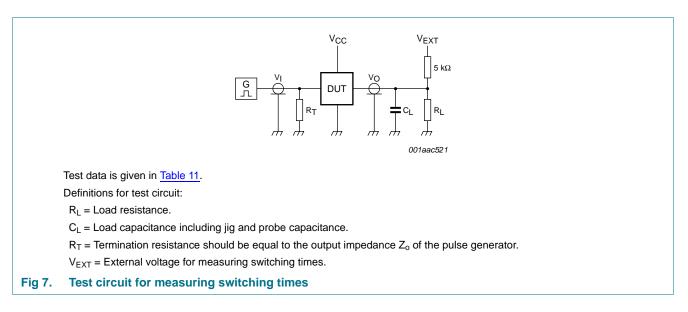
Low-power 1-of-2 demultiplexer with 3-state deselected output



#### Table 10. Measurement points

Supply voltage Input		Output				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
0.8 V to 1.6 V	$0.5  imes V_{CC}$	$0.5\times V_{CC}$	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> – 0.1 V		
1.65 V to 2.7 V	$0.5\times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V		
3.0 V to 3.6 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V		

#### Low-power 1-of-2 demultiplexer with 3-state deselected output



#### Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	RL <sup>[1]</sup>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times  $R_L = 5 k\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 M\Omega$ .

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### 13. Package outline

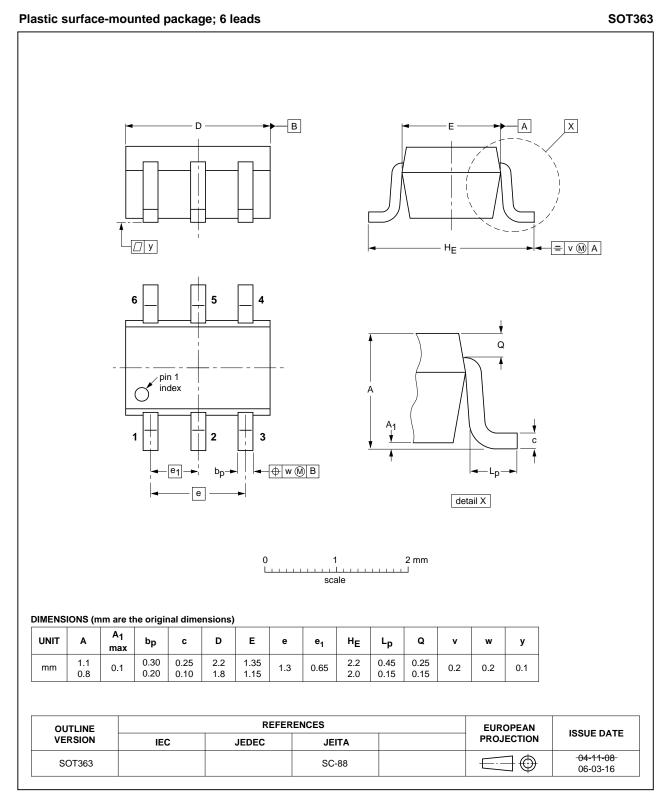
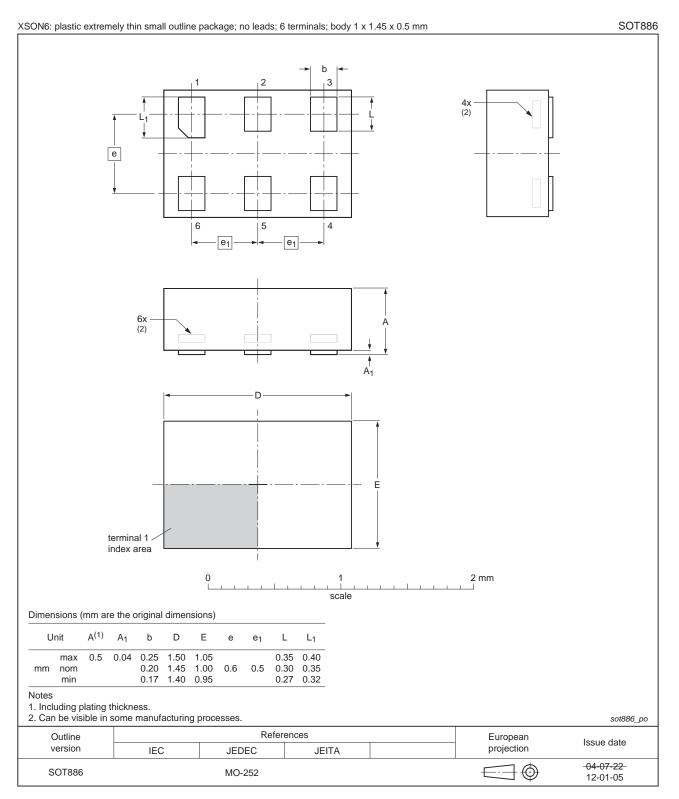


Fig 8. Package outline SOT363 (SC-88)

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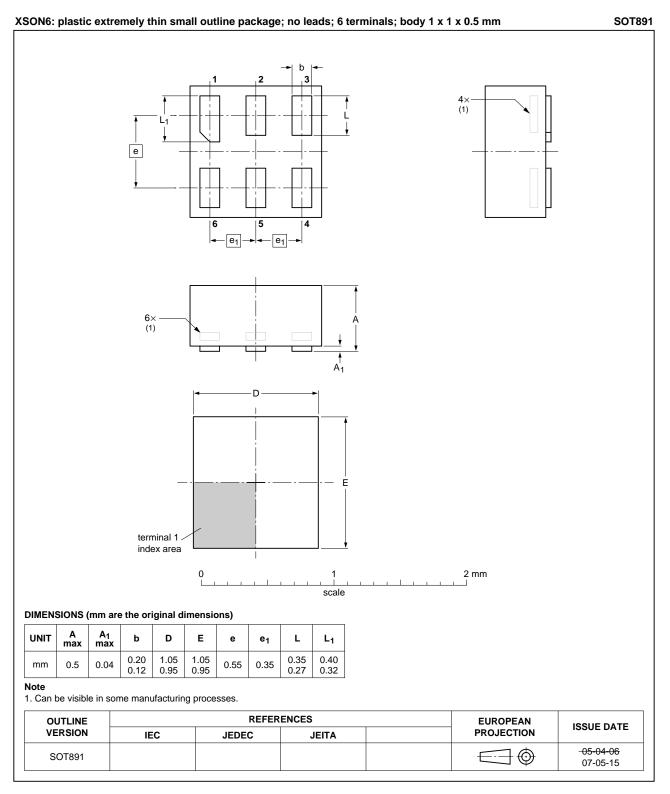
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#### Fig 9. Package outline SOT886 (XSON6)

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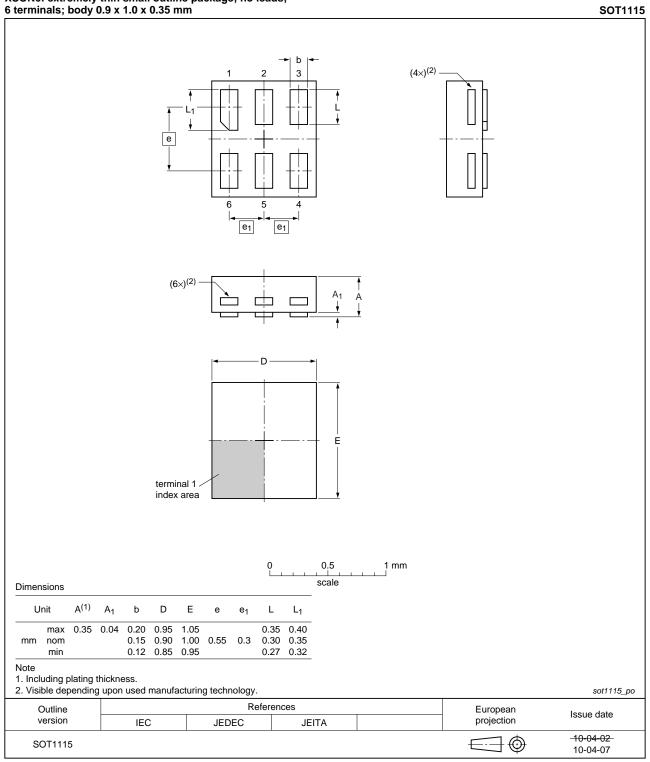


#### Fig 10. Package outline SOT891 (XSON6)

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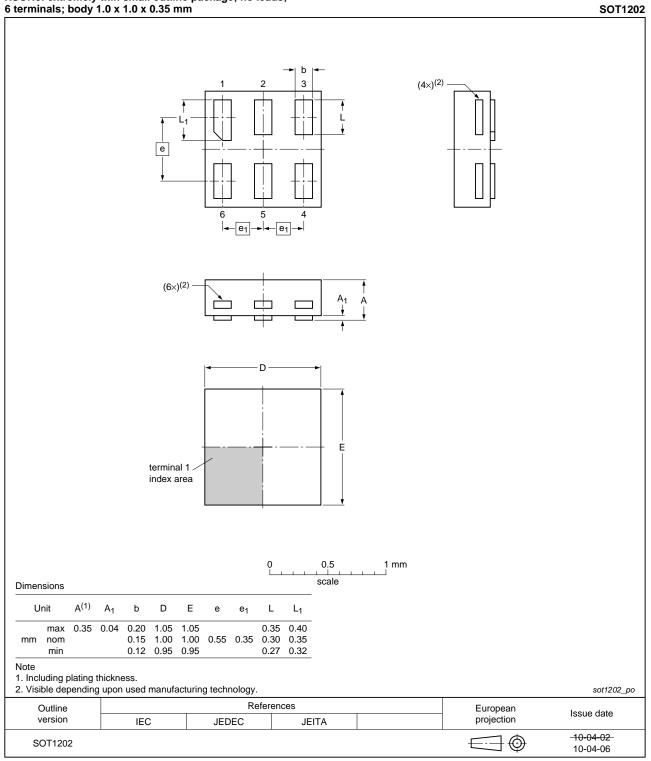


# XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 11. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 12. Package outline SOT1202 (XSON6)

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### 14. Abbreviations

AcronymDescriptionCDMCharged Device ModelDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Table 12. A	obreviations	
DUTDevice Under TestESDElectroStatic DischargeHBMHuman Body Model	Acronym	Description	
ESDElectroStatic DischargeHBMHuman Body Model	CDM	Charged Device Model	
HBM Human Body Model	DUT	Device Under Test	
	ESD	ElectroStatic Discharge	
MM Machina Madal	HBM	Human Body Model	
	MM	Machine Model	

## **15. Revision history**

#### Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G18 v.5	20120703	Product data sheet	-	74AUP1G18 v.4
Modifications:	<ul> <li>Package ou</li> </ul>	tline drawing of SOT886 (	Figure 9) modified.	
74AUP1G18 v.4	20111124	Product data sheet	-	74AUP1G18 v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	s updated.		
74AUP1G18 v.3	20100927	Product data sheet	-	74AUP1G18 v.2
74AUP1G18 v.2	20080403	Product data sheet	-	74AUP1G18 v.1
74AUP1G18 v.1	20061013	Product data sheet	-	-

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### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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#### Low-power 1-of-2 demultiplexer with 3-state deselected output

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